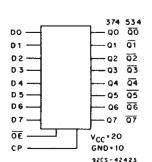
Data sheet acquired from Harris Semiconductor SCHS290

TRUMENTS



Octal D-Type Flip-Flops, 3-State

Positive-Edge Triggered

CD54/74AC/ACT374 - Non-Inverting CD54/74AC/ACT534 - Inverting

Type Features:

- Buffered inputs
- Typical propagation delay: 5 ns @ V_{CC} = 5 V, T_A = 25° C, C_L = 50 pF

FUNCTIONAL DIAGRAM

74AC/ACT574.)

Family Features:

- Exceeds 2-kV ESD Protection MIL-STD-883, Method 3015
- SCR-Latch-up-resistant CMOS process and circuit design
 Speed of bipolar FAST*/AS/S with significantly
- reduced power consumption
- Balanced propagation delays
- AC types feature 1.5-V to 5.5-V operation and balanced noise immunity at 30% of the supply
- ± 24-mA output drive current
 - Fanout to 15 FAST* ICs
 - Drives 50-ohm transmission lines

*FAST is a Registered Trademark of Fairchild Semiconductor Corp.

The CD74AC/ACT374 and CD74AC/ACT534 are supplied in 20-lead dual-in-line plastic packages (E suffix) and in 20-lead dual-in-line small-outline plastic packages (M suffix). Both package types are operable over the following temperature ranges: Commercial (0 to 70°C); Industrial (-40 to +85°C); and Extended Industrial/Military (-55 to +125°C).

The RCA-CD54/74AC374 and CD54/74AC534 and the

CD54/74ACT374 and CD54/74ACT534 octal D-type, 3-state,

positive-edge triggered flip-flops use the RCA ADVANCED

CMOS technology. The eight flip-flops enter data into their

registers on the LOW-to-HIGH transition of the clock (CP).

The Output Enable (OE) controls the 3-state outputs and is

independent of the register operation. When the Output

Enable (OE) is HIGH, the outputs are in the high-impedance

state. The CD54/74AC/ACT374 and CD54/74AC/ACT534

share the same pin configurations, but the CD54/74AC/

ACT374 outputs are non-inverted while the CD54/74AC/

ACT534 devices have inverted outputs. (For flow-through

pin configurations, see CD54/74AC/ACT564 and CD54/

The CD54AC/ACT374 and CD54AC/ACT534, available in chip form (H suffix), are operable over the -55 to +125×C temperature range.

TRUTH TABLE

	INPUTS	OUTPUTS				
		374	534			
ŌE	СР	Dn	Qn	Qn		
L		Н	Н	L		
L		L	L	Н		
L	L	Х	QO	QO		
Н	X	Х	Z	Z		

H = High level (steady state)

L = Low level (steady state)

X = Don't care

= Transition from low to high level

QO = The level of Q before the indicated steady-state input conditions were established

Z = High impedance

(

MAXIMUM RATINGS, Absolute-Maximum Values:
DC SUPPLY-VOLTAGE (Vcc)0.5 to 6 V
DC INPUT DIODE CURRENT. I_{IK} (for $V_1 < -0.5 \text{ V}$ or $V_1 > V_{CC} + 0.5 \text{ V}$) $\pm 20 \text{ mA}$
DC OUTPUT DIODE CURRENT. low (for $V_0 < -0.5$ V or $V_0 > V_{cc} + 0.5$ V)
DC OUTPUT SOURCE OR SINK CURRENT per Output Pin, Io (for $V_0 > -0.5 \text{ V}$ or $V_0 < V_{CC} + 0.5 \text{ V}$) $\pm 50 \text{ mA}$
DC Vcc or GROUND CURRENT (Icc or IGND)
POWER DISSIPATION PER PACKAGE (P₀):
FOR $T_A = -55$ to $+100$ °C (PACKAGE TYPE E)
For T _A = +100 to +125°C (PACKAGE TYPE E) Detaile Linearly at 8 mW/ C to 300 mW
For T _A = -55 to +70°C (PACKAGE TYPE M)
For T _A = +70 to +125°C (PACKAGE TYPE M) Derate Linearly at 6 mW/°C to 70 mW
OPERATING-TEMPERATURE RANGE (T _A)55 to +125°C
STORAGE TEMPERATURE (T _{stg})65 to +150°C
LEAD TEMPERATURE (DURING SOLDERING):
At distance $1/16 \pm 1/32$ in. $(1.59 \pm 0.79 \text{ mm})$ from case for 10 s maximum
Unit inserted into PC board min. thickness 1/16 in. (1.59 mm) with solder contacting lead tips only +300°C
*For up to 4 outputs per device; add \pm 25 mA for each additional output.

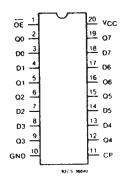
RECOMMENDED OPERATING CONDITIONS:

For maximum reliability, normal operating conditions should be selected so that operation is always within the following ranges:

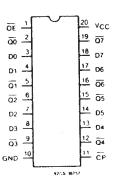
	LIM	ITS	UNITS	
CHARACTERISTIC	1.5 5.5 4.5 5.5 0 V _{cc} -55 +125	DIVITS		
Supply-Voltage Range, V _{cc} *: (For T _A = Full Package-Temperature Range) AC Types ACT Types	•	1	V	
DC Input or Output Voltage, V _I , V _O	0	Vcc	V	
Operating Temperature, TA	-55	+125	°C	
Input Rise and Fall Slew Rate, dt/dv at 1.5 V to 3 V (AC Types) at 3.6 V to 5.5 V (AC Types) at 4.5 V to 5.5 V (ACT Types)	i -		ns/V ns/V ns/V	

^{*}Unless otherwise specified, all voltages are referenced to ground.

TERMINAL ASSIGNMENT DIAGRAMS



CD54/74AC/ACT374



CD54/74AC/ACT534

STATIC ELECTRICAL CHARACTERISTICS: AC Series

		1			AMBIENT TEMPERATURE (TA) - °C						
CHARACTERIST	ICS	TEST CO	NDITIONS	V _{cc}	+	25	-40 1	o +85	-55 to +125		UNITS
		(V)	l _o (mA)	(V)	MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input				1.5	1.2	_	1.2	_	1.2	<u> </u>	
Voltage	V _{IH}			3	2.1	_	2.1	<u> </u>	2.1		l v
				5.5	3.85	-	3.85	_	3.85	<u> </u>	7
Low-Level Input				1.5		0.3	T —	0.3	1 –	0.3	
Voltage	V _{IL}			3	_	0.9	_	0.9		0.9	1 v
			l	5.5	_	1.65	_	1.65	l –	1.65	1
High-Level Output			-0.05	1.5	1.4	l –	1.4	<u> </u>	1.4	T -	
Voltage	V _{OH}	ViH	-0.05	3	2.9		2.9		2.9	_	1
		or	-0.05	4.5	4.4		4.4		4.4		1
		VıL	-4	3	2.58	_	2.48	_	2.4		l v
			-24	4.5	3.94		3.8	_	3.7	_	1
		#, * {	-75	5.5	_		3.85	_		_	1
		" , " {	-50	5.5	_		-		3.85		1
Low-Level Output			0.05	1.5	_	0.1		0.1		0.1	
Voltage	Vol	V _{IH}	0.05	3	_	0.1	_	0.1	_	0.1	1
		or	0.05	4.5	_	0.1	_	0.1	_	0.1	1
		Vil	12	3	_	0.36	_	0.44	_	0.5	- v
			24	4.5	-	0.36	_	0.44	_	0.5	
		#, * {	75	5.5	_	_		1.65		_	ĺ
		"' {	50	5.5	_	_		_	_	1.65	
Input Leakage Current	Į,	V _{cc} or GND		5.5		±0.1	_	±1		±1	μΑ
3-State Leakage Current	loz	V _{IH}									
ountin	102	or									
		V _{IL}									
		$V_0 =$		5.5	- 1	±0.5	-	±5	-	±10	μΑ
		Vcc									l
		or]	ļ	
		GND									
Quiescent Supply Current, MSI	loc	V _{CC} or GND	0	5.5	-	8		80	-	160	μΑ

[#]Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize power dissipation.

* Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

Technical Data _

CD54/74AC374, CD54/74AC534 CD54/74ACT374, CD54/74ACT534

STATIC ELECTRICAL CHARACTERISTICS: ACT Series

						AMBIENT	TEMPE	RATURE	(T _A) - °(<u> </u>	
CHARACTERISTI	cs	TEST CONDITIONS		V _{cc}	+25		-40 to +85		-55 to +125		UNITS
		V, (V)	l _o (mA)	(V)	MłN.	MAX.	MIN.	MAX.	MIN.	MAX.	
High-Level Input Voltage	ViH			4.5 to 5.5	2		2		2	_	v
Low-Level Input Voltage	V _{IL}			4.5 to 5.5	_	0.8		0.8	_	0.8	V
High-Level Output		V _{IH}	-0.05	4.5	4.4	_	4.4		4.4		
Voltage	V _{OH}	or V _{ii}	-24	4.5	3.94		3.8		3.7		V
			-75	5.5	_		3.85				
		#, ^ {	-50	5.5 — — — — 3.85							
Low-Level Output Voltage Vol	V _{IH}	0.05	4.5	_	0.1		0.1		0.1		
	or V _{IL}	24	4.5	_	0.36	_	0.44		0.5	l v	
	1 1	75	5.5			_	1.65				
		#, * {	50	5.5	_		_	_		1.65	
Input Leakage Current	~ I ₁	V _{cc} or GND		5.5	_	±0.1	_	±1		±1	μΑ
3-State Leakage Current	łoz	V _{IH} or V _{IL} V _O = V _{CC} or GND		5.5		±0.5		±5	_	±10	μΑ
Quiescent Supply Current, MSI	Icc	V _{cc} or GND	0	5.5		8		80	_	160	μΑ
Additional Quiescent Current per Input P TTL Inputs High 1 Unit Load		V _{cc} -2.1		4.5 to 5.5	_	2.4		2.8		3	mA

[#]Test one output at a time for a 1-second maximum duration. Measurement is made by forcing current and measuring voltage to minimize

ACT INPUT LOADING TABLE

INPUT	UNIT LOADS*
D, ŌĒ	0.7
СР	1.17

^{*}Unit load is ΔI_{CC} limit specified in Static Characteristics Chart, e.g., 2.4 mA max. @ 25° C.

power dissipation.

* Test verifies a minimum 50-ohm transmission-line-drive capability at +85°C, 75 ohms at +125°C.

PREREQUISITE FOR SWITCHING: AC Series

			AMBI	A) - °C			
CHARACTERISTICS	SYMBOL	V _{cc} (V)	-40 to +85		-55 to +125		UNITS
			MIN.	MAX.	MIN.	MAX.	1
Clock Pulse Width	tw	1.5 3.3* 5†	44 4.9 3.5		50 5.6 4		ns
Setup Time Data to Clock	tsu	1.5 3.3 5	2 2 2	=	2 2 2		ns
Hold Time Data to Clock	t _H	1.5 3.3 5	2 2 2		2 2 2	_ _ _	ns
Maximum Clock Frequency	f _{MAX}	1.5 3.3 5	11 101 143		10 89 125		MHz

*3.3 V: min. is @ 3 V †5 V: min. is @ 4.5 V

SWITCHING CHARACTERISTICS: AC Series; t_r , t_t = 3 ns, C_t = 50 pF

			AMBI	ENT TEMPE	RATURE (1	(A) - °C	
CHARACTERISTICS	SYMBOL	V _{cc} (V)	-40 t	-40 to +85		-55 to +125	
		(*)	MIN.	MAX.	MIN.	MAX.	1
Propagation Delays: Clock to Q AC374	t _{PLH}	1.5 3.3* 5†	3.9 2.8	123 13.7 9.8	— 3.8 2.7	135 15.1 10.8	ns
Clock to Q AC534	t _{PLH} t _{PHL}	1.5 3.3 5	 4.1 2.9	128 14.4 10.3	_ 4 2.8	141 15.8 11.3	ns
Output Enable to Q, Q	tpzL tpzH	1.5 3.3 5	5.6 3.7	165 19.8 13.2	 5.5 3.6	181 21.8 14.5	ns
Output Disable to Q, Q	t _{PLZ}	1.5 3.3 5	4.7 3.7	165 16.5 13.2	4.5 3.6	181 18.1 14.5	ns
Power Dissipation Capacitance	Ceo§	_	67	Гур.	67	Тур.	pF
Min. (Valley) V _{OH} During Switching of Other Outputs (Output Under Test Not Switching)	V _{онv} See Fig. 1	5	4 Typ. @ 25°C		V		
Max. (Peak) Vol During Switching of Other Outputs (Output Under Test Not Switching)	V _{OLP} See Fig. 1	5		1 Тур. (@ 25°C		٧
Input Capacitance	Cı	_		10		10	pF
3-State Output Capacitance	Co		_	15	_	15	pF

*3.3 V: min. is @ 3.6 V

max. is @ 3 V

†5 V: min. is @ 5.5 V

max. is @ 4.5 V

§C_{PD} is used to determine the dynamic power consumption, per flip flop.

 $P_D = C_{PD} V_{CC}^2 f_i + \Sigma V_{CC}^2 f_0 C_L$ where $f_i = input frequency$

fo = output frequency

C_L = output load capacitance V_{cc} = supply voltage.

PREREQUISITE FOR SWITCHING: ACT Series

-		V _{cc}	AMBII	,				
CHARACTERISTICS	SYMBOL		-40 to +85		-55 to +125		UNITS	
			MIN.	MAX.	- MIN.	MAX.		
Clock Pulse Width	t _w	5†	3.9	_	4.5	_	. ns	
Setup Time Data to Clock	tsu	5	2	<u> </u>	2	_	ns	
Hold Time Data to Clock	t _H	5	2.6	_	3	_	ns	
Maximum Clock Frequency	f _{MAX}	5	125	_	110	_	MHz	

15 V: min. is @ 4.5 V

SWITCHING CHARACTERISTICS: ACT Series; t,, t, = 3 ns, C, = 50 pF

			AMBI	AMBIENT TEMPERATURE (TA) - °C				
CHARACTERISTICS	SYMBOL	V _{cc}	-40 to +85		-55 to +125		UNITS	
			MIN.	MAX.	MIN.	MAX.	1	
Propagation Delays: Clock to Q ACT374	tегн. tенг	5†	2.9	10.2	2.8	11.2	ns	
Clock to Q ACT534	t _{PLH}	5	3	10.6	2.9	11.7	ns	
Output Enable and Disable to Q ACT374	tplz tpHz tpZL tpZH	5	3.7	13.2	3.6	14.5	ns	
Output Enable and Disable to Q ACT534	tplz tpHz tpZL tpZH	5	3.7	13.2	3.6	14.5	ns	
Power Dissipation Capacitance	C _{PD} §		67	Тур.	67	Тур.	pF	
Min. (Valley) V _{он} During Switching of Other Outputs (Output Under Test Not Switching)	V _{онv} See Fig. 1	5	4 Typ. @ 25°C		V			
Max. (Peak) Vol. During Switching of Other Outputs (Output Under Test Not Switching)	V _{OLP} See Fig. 1	5		1 Typ. (@ 25°C		v	
Input Capacitance	Ci	-		10	_	10	ρF	
3-State Output Capacitance	Co	_	_	15	_	15	pF	

†5 V: min. is @ 5.5 V max. is @ 4.5 V

§C_{PD} is used to determine the dynamic power consumption, per flip flop.

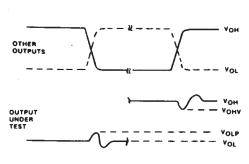
 $P_D = C_{PD} V_{CC}^2 f_i + V_{CC}^2 f_0 C_L + V_{CC} \Delta I_{CC}$ where $f_i = input$ frequency

 $f_0 = output$ frequency

C_L = output load capacitance

 V_{CC} = supply voltage.

PARAMETER MEASUREMENT INFORMATION



NOTES:

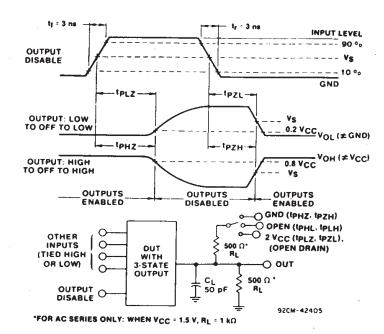
- NOTES:

 1. YOMY AND YOLP ARE MEASURED WITH RESPECT TO A GROUND REFERENCE NEAR THE OUTPUT UNDER TEST.

 2. INPUT PULSES MAVE THE FOLLOWING CHARACTERISTICS: PAR < 1 MHA. 1, -1 an. 1, -1 an. 5 KEW 1 ns.

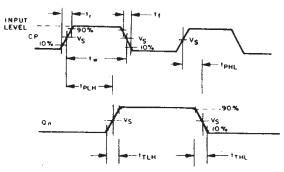
 3. R.F. FIXTURE WITH 700-MHz DESIGN RULES REQUIRED. IC SHOULD BE SOLDERED INTO TEST BOARD AND BYPASSED WITH 0.1 IF CAPACITOR. SCOPE AND PROBES REQUIRE 700-MHz BANDWIDTH.

9205-42406

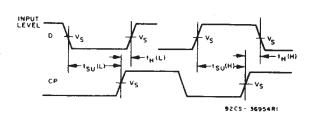


*For AC series only: When V_{CC} = 1.5V, R_L = 1 k Ω

Fig. 1 - Simultaneous switching transient waveforms. Fig. 2 - Three-state propagation delay waveforms and test circuit.



92 CS - 38404 RI



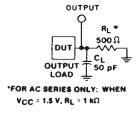


Fig. 3 - Propagation delay times and test circuit.

	CD54/74AC	CD54/74ACT
Input Level	V _{cc}	3 V
Input Switching Voltage, Vs	0.5 V _{CC}	1.5 V
Output Switching Voltage, Vs	0.5 V _{cc}	0.5 V _{cc}

PACKAGE OPTION ADDENDUM



i.com 26-Sep-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD54AC374F3A	ACTIVE	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
CD54ACT374F3A	ACTIVE	CDIP	J	20	1	TBD	Call TI	Level-NC-NC-NC
CD54ACT534F3A	OBSOLETE	CDIP	J	20		TBD	Call TI	Call TI
CD74AC374E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74AC374EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74AC374M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC374M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC374M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC374ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC534M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74AC534M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	Level-NC-NC-NC
CD74ACT374M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74ACT374ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE OPTION ADDENDUM

26-Sep-2005

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14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



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